

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector-Emitter Voltage	VCEO	15	Vdc	
Collector-Base Voltage	VCBO	30	Vdc	
Emitter-Base Voltage	VEBO	2.5	Vdc	
Collector Current — Continuous	lc_	40	mAdc	
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	200 1.14	m₩ mW/°C	
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	PD	300 1.72	mW mW/°C	
Storage Temperature	Tstg	-65 to +200	°C	

## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted.)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector-Emitter Breakdown Voltage* (IC = 3.0 mAdc, IB = 0)		V(BR)CEO	15	_	-	Vdc
Collector-Base Breakdown Voltage ( $I_C = 1.0 \mu Adc, I_E = 0$ )		V(BR)CBO	30	—	-	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 10 \ \mu Adc, I_C = 0$ )		V(BR)EBO	2.5	—	-	Vdc
	Both Types 2N3839	Ісво	_	_	0.01 1.0	μAdc
ON CHARACTERISTICS						
DC Current Gain (IC = 3.0 mAdc, $V_{CE}$ = 1.0 Vdc)		hFE	30	-	150	-
SMALL SIGNAL CHARACTERISTICS	-					
	2N2857 2N3839	fτ	1000 1000	_	- 1900 2000	MHz
Collector-Base Capacitance (V <sub>CB</sub> = 10 Vdc, $I_E$ = 0, f = 0.1 to 1.0 MHz)		C <sub>cb</sub>	_	0.7	1.0	pF
Small Signal Current Gain (I <sub>C</sub> = 2.0 mAdc, $V_{CE}$ = 6.0 Vdc, f = 1.0 kHz)		h <sub>fe</sub>	50	-	220	-
	2N2857 2N3839	rb′C <sub>C</sub>	4.0 1.0		15 15	ps
Noise Figure (Figure 1) ( $I_E = 0.1 \text{ mAdc}$ , $V_{CE} = 1.0 \text{ Vdc}$ , $R_S = 50 \text{ ohms}$ , $f = 450 \text{ MHz}$ )(2) ( $I_C = 1.5 \text{ mAdc}$ , $V_{CE} = 6.0 \text{ Vdc}$ , $R_S = 50 \text{ ohms}$ , $f = 450 \text{ MHz}$ )		NF	_	5.8 4.1		dB

Common-Emitter Amplifier Power Gain (Figure 1)	Gpe				dB
$(I_E = 0.1 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}, f = 450 \text{ MHz}, R_S = 50\Omega))(2)$			11		
$(I_{C} = 1.5 \text{ mAdc}, V_{CE} = 6.0 \text{ Vdc}, f = 450 \text{ MHz}, R_{S} = 50\Omega)$		12.5	-	19	
Power Output (Figure 2)	Pout	30	-	—	mW
$(I_E = 12 \text{ mAdc}, V_{CB} = 10 \text{ Vdc}, f = 500 \text{ MHz})$					

(1) fT is defined as the frequency at which |hfe| extrapolates to unity.

(2) Micro-Power Specifications.
\*Indicates Data in addition to JEDEC Requirements.

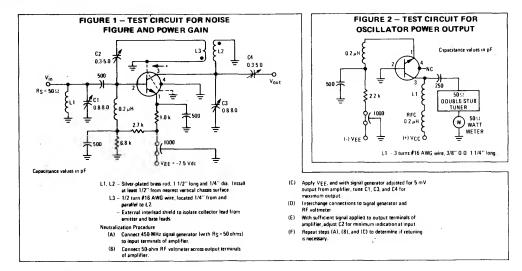


FIGURE 3 - NOISE FIGURE versus FREQUENCY

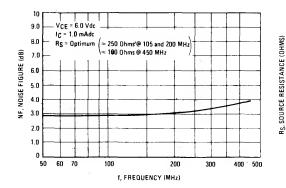
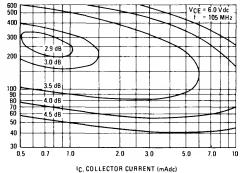
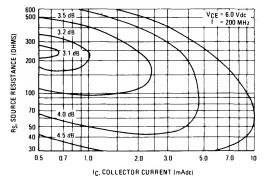


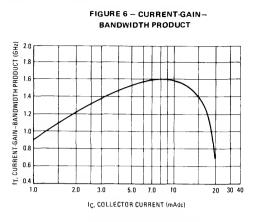
FIGURE 4 - NOISE FIGURE versus SOURCE RESISTANCE AND COLLECTOR CURRENT



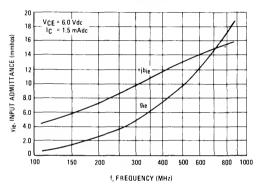
## FIGURE 5 - NOISE FIGURE versus SOURCE RESISTANCE AND COLLECTOR CURRENT



## 2N2857 • 2N3839









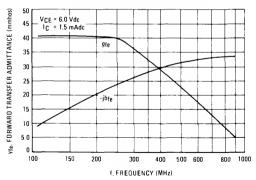


FIGURE 7 - NOISE FIGURE AND POWER GAIN

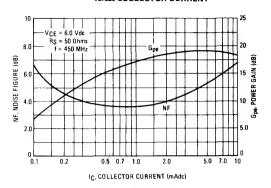


FIGURE 9 – OUTPUT ADMITTANCE versus FREQUENCY

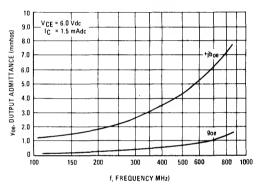
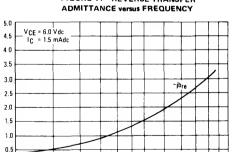


FIGURE 11 -REVERSE TRANSFER



300 400 f, FREQUENCY (MHz)

400 500 600

-9re

800 1000

(mmhos)

TRANSFER ADMITTANCE

REVERSE

yre,

0

100

150

200

